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April 2016

FFPF10F150S 10 A, 1500 V, Damper Diode

Features

- High Speed Recovery t_{rr} = 170 ns (@ I_F = 1 A)
- Max Forward Voltage, V_F = 1.6 V (@ T_C = 25°C)
- 1500 V Reverse Voltage and High Reliability
- Low Forward Voltage

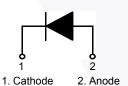
Applications

• Suitable for Damper Diode in Horizontal Deflection Circuits

Pin Assignments



1. Cathode 2. Anode



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Rating	Unit
V _{RRM}	Peak Repetitive Reverse Voltage	1500	V
V_{RWM}	Working Peak Reverse Voltage	1500	V
I _{F(AV)}	Average Rectified Forward Current @ T _C = 125 °C	10	Α
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	100	Α
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Thermal Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.0	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF10F150STU	F10F150S	TO-220F-2L	Tube	N/A	N/A	30

Electrical Characteristics T_C = 25°C unless otherwise noted

Parameter	Conditions			Тур.	Max.	Unit
V _F ¹	Maximum Instantaneous Forward Voltage $I_F = 10 \text{ A}$ $I_F = 10 \text{ A}$	T _C = 25 °C T _C = 125 °C		-	1.6 1.4	٧
I _R ¹	Maximum Instantaneous Reverse Current @ rated V _R	T _C = 25 °C T _C = 125 °C			10 80	μΑ
t _{rr}	Maximum Reverse Recovery Time $(I_F = 1 \text{ A, di}_F/\text{dt} = 50 \text{ A/}\mu\text{s, V}_R = 30 \text{ V})$		-	-	170	ns
t _{fr}	Maximum Forward Recovery Time (I _F = 6.5 A, di _F /dt = 50 A/µs)		-	-	250	ns
V _{FRM}	Maximum Forward Recovery Voltage		-	-	14	V

Notes:

1. Pulse : Test Pulse Width = $300\mu s$, Duty Cycle = 2%

Test Circuit and Waveforms

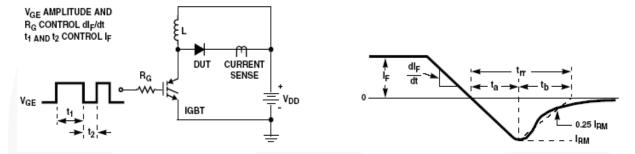


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

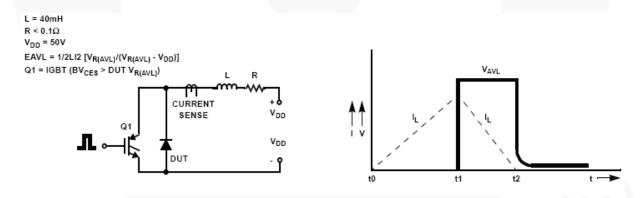


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

Typical Performance Characteristics T_C = 25°C unless otherwise noted

Figure 3. Typical Forward Voltage Drop

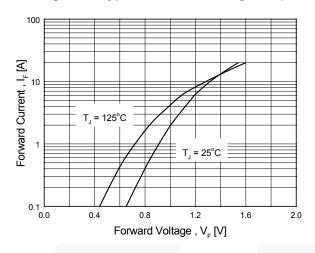


Figure 4. Typical Reverse Current

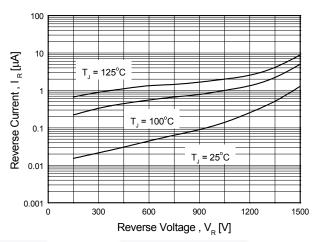


Figure 5. Typical Junction Capacitance

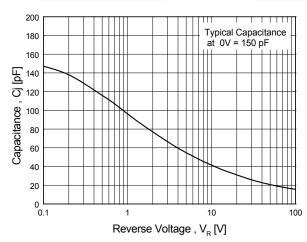


Figure 6. Typical Reverse Recovery Time

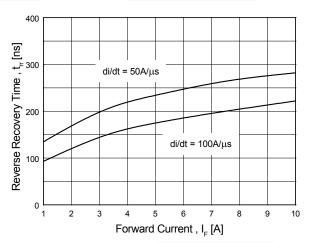


Figure 7. Typical Stored Charge

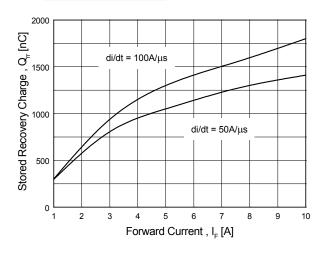
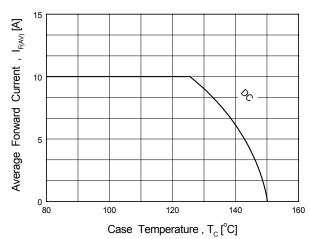
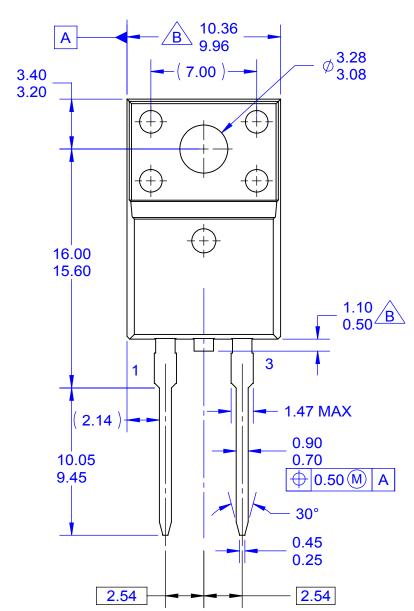


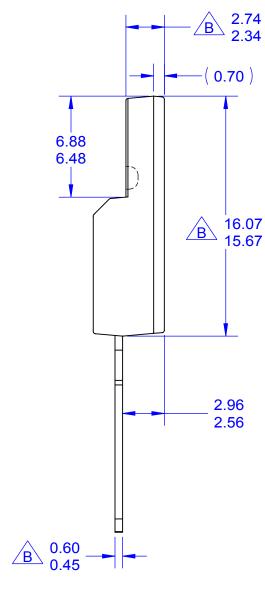
Figure 8. Forward Current Deration Curve



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1	RELEASED TO DCC	08JUL08	H.ALLEN.FSME		
2	COMPLETE REDRAW	14APR09	KH LEE/ SUZHOU		





NOTES:

4.90

4.50

/B

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- B DOES NOT COMPLY EIAJ STD. VALUE.
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